



Characterization of JadePix-3 CMOS Pixel Sensor for the CEPC Vertex Detector

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5th Semiconductor Radiation Detector Symposium

4/19/2025



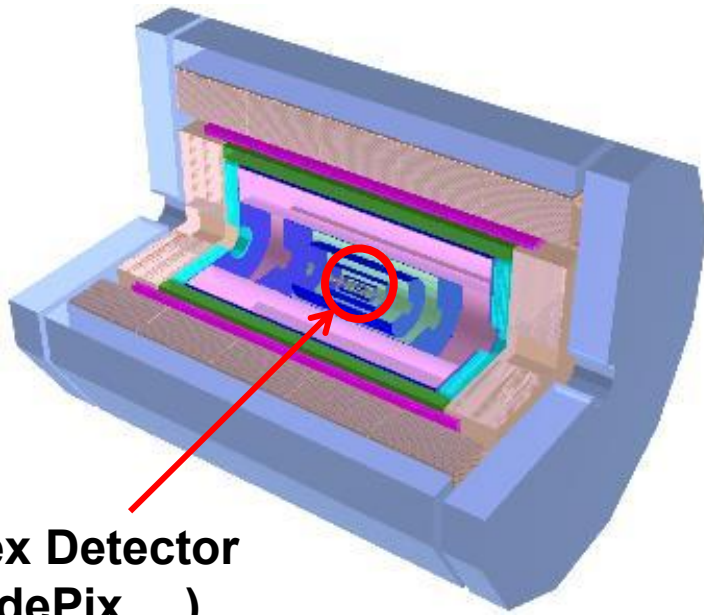
Outline

- **Requirements & Design**
 - R&D background of JadePix-3
 - Design specifications of JadePix-3 MAPS
- **Performance Test @USTC**
 - Motivation for substrate reverse bias test
 - Test result
- **Summary & Outlook**

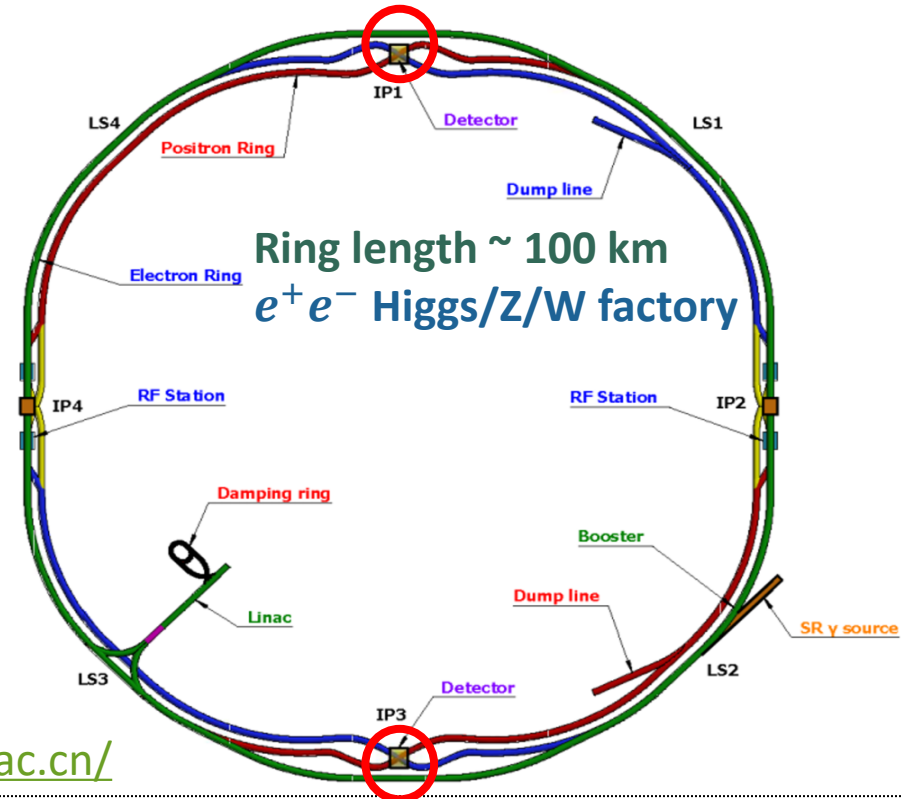


The Circular Electron Positron Collider (CEPC)

- The **CEPC** was proposed in 2012 right after the Higgs discovery. It aims to start operation in 2030s, as an e^+e^- Higgs / Z / W factory.
- The **JadePix-3** sensors are orientated to the vertex detector for the experiments at the proposed future CEPC for precise measurement of Higgs boson.



Vertex Detector
(JadePix ...)



<http://cepc.ihep.ac.cn/>



R&D background of JadePix pixel chip

Impact parameter resolution

Measurement of $Br(H \rightarrow bb/cc)$ strongly depends on vertex detector parameter:

$$\sigma_{r\phi} = 5\mu m \oplus \frac{10}{p(GeV) \sin^{3/2} \theta} \mu m$$

Vertex detector specs

$\sigma_{s.p.} \sim 2.8\mu m$

Material budget $\sim 0.15\% X_0/\text{layer}$

r of Inner most layer $\sim 16\text{mm}$

Pixel sensor specs

JadePix-3

Small pixel $\sim 16\mu m$

Thinning to $\sim 50\mu m$

low power $\sim 50\text{mW}/\text{cm}^2$

fast readout $\sim 1\mu s$

JadePix-4

radiation tolerance $\sim$

$\leq 3.4 \text{ Mrad/year}$

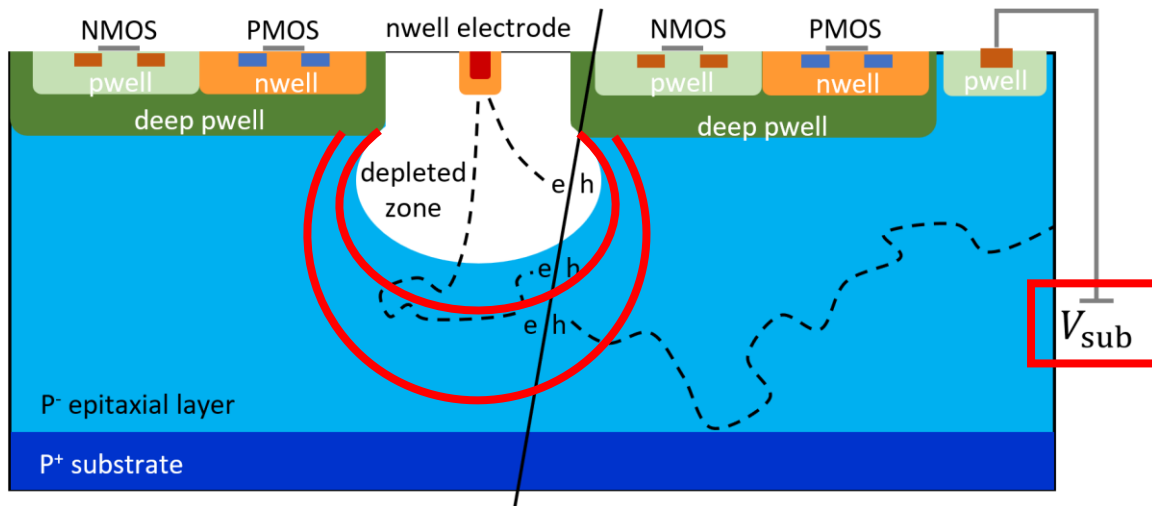
$\leq 6.2 \times 10^{12} n_{eq}/(\text{cm}^2 \text{ year})$

• JadePix-3 CDR: (Requirements)

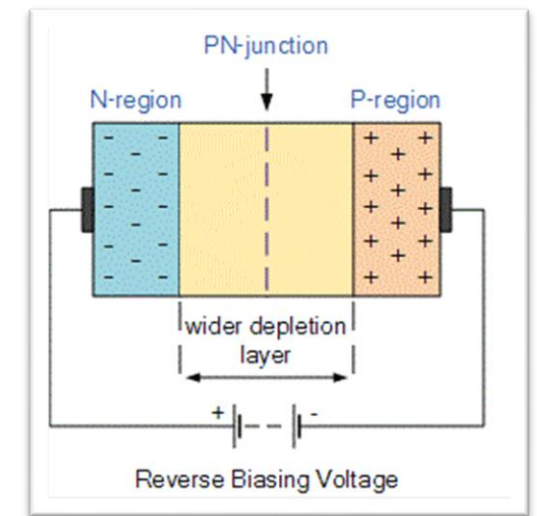
- **Small pixel** + **Thin chip** + **Low power**
- Only **MAPS** technology can meet these requirements
- What is MAPS?

Monolithic Active Pixel Sensors MAPS

- It is called Monolithic technology because sensors and readout electronics are integrated on one chip.
- Advantages:
 - **Smaller Pixel Size** and **Low material budget**
 - **Lower Costs** : implemented in standard commercial CMOS processes
 - **Bias Voltage**: added to substrate to improve performance by expanding *depleted zone*



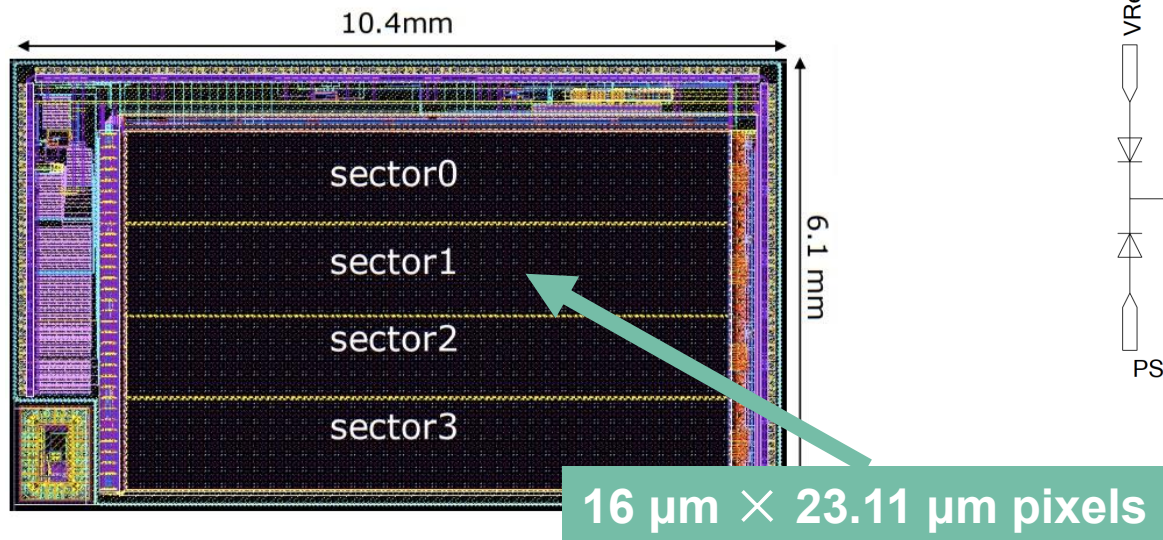
**Sensing diode of JadePix-3
(High-resistivity CMOS)**



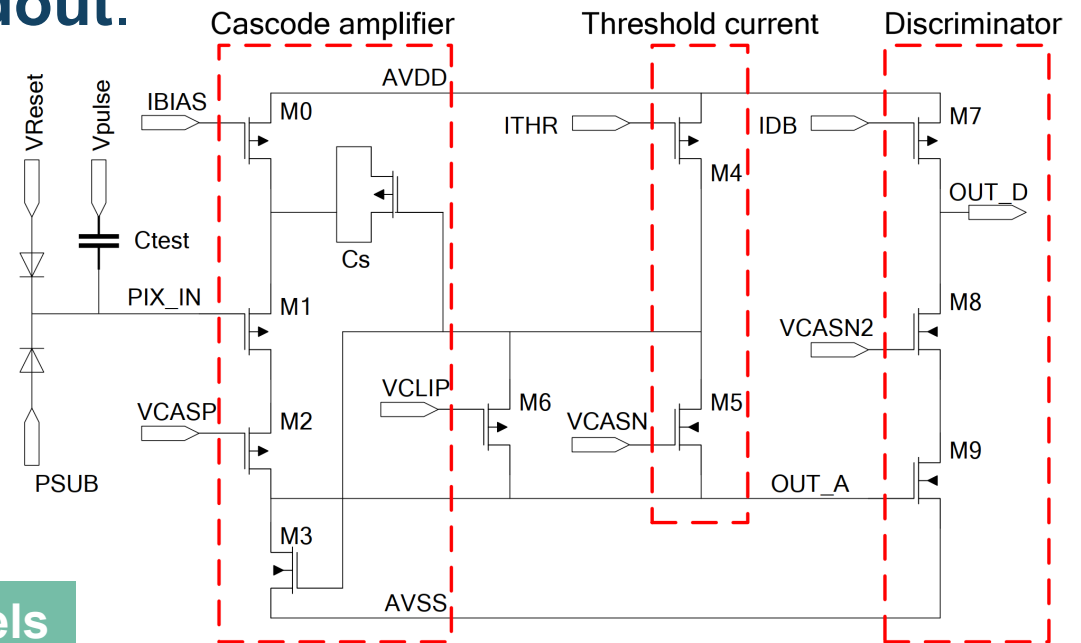
Design specs of JadePix-3 MAPS

P. Yang, Y. Zhang, Y. Zhou, L. Xiao, L. Zhang, Z. Shi, D. Guo, Z. Wu, Yunpeng LU

- JadePix-3 optimized for **position resolution** and **low power consumption** with Tower Jazz 180nm process.
 - Minimum pixel size: **$16\ \mu\text{m} \times 23.11\ \mu\text{m}$**
 - Matrix readout time: **$98.3\ \mu\text{s}/\text{frame}$**
- ALPIDE-like front-end with **binary readout**.



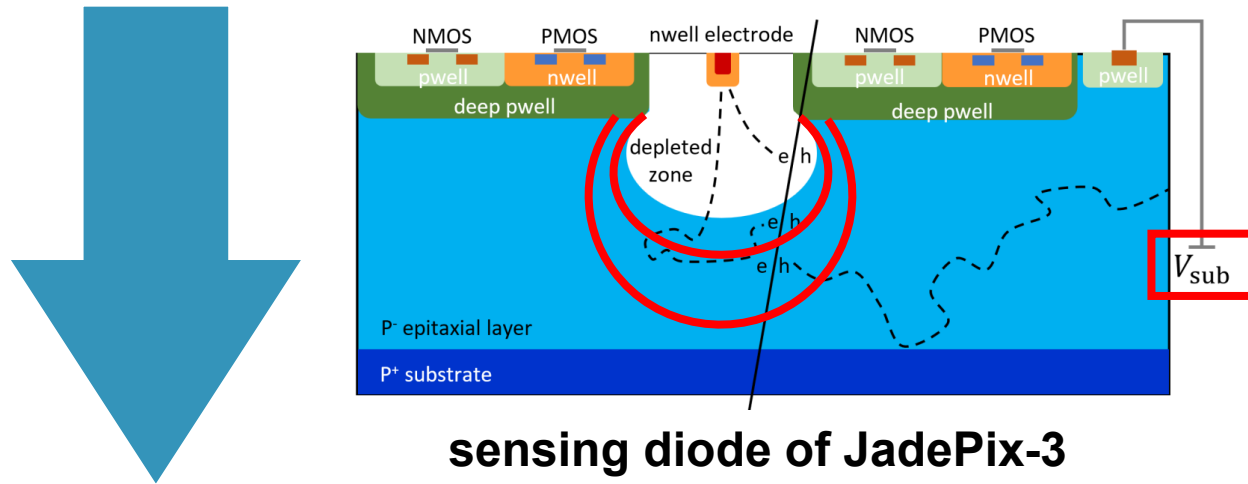
Layout of the JadePix-3 sensor



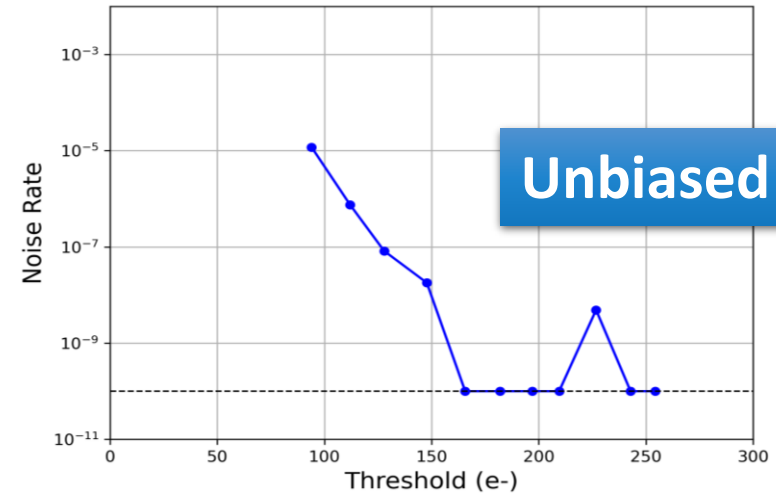
Analog front-end of the sensor

Motivation

- **Bias Voltage** added to the substrate should **improve** performance metrics:
 - (front-end) Noise, Input Capacitance
 - (detection) Detection Efficiency, Charge Collection Efficiency
 - Radiation Tolerance
 -
- Unbiased test done previously @NIMA 1048 (2023) 167967



sensing diode of JadePix-3

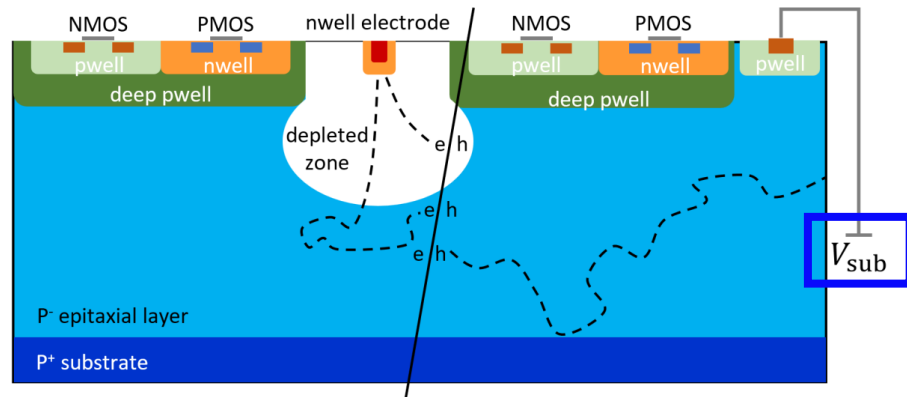
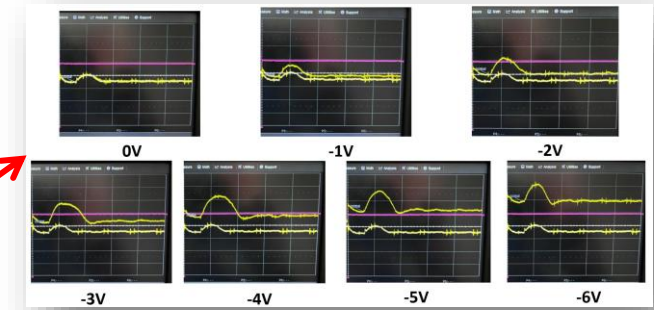


Previous Noise test

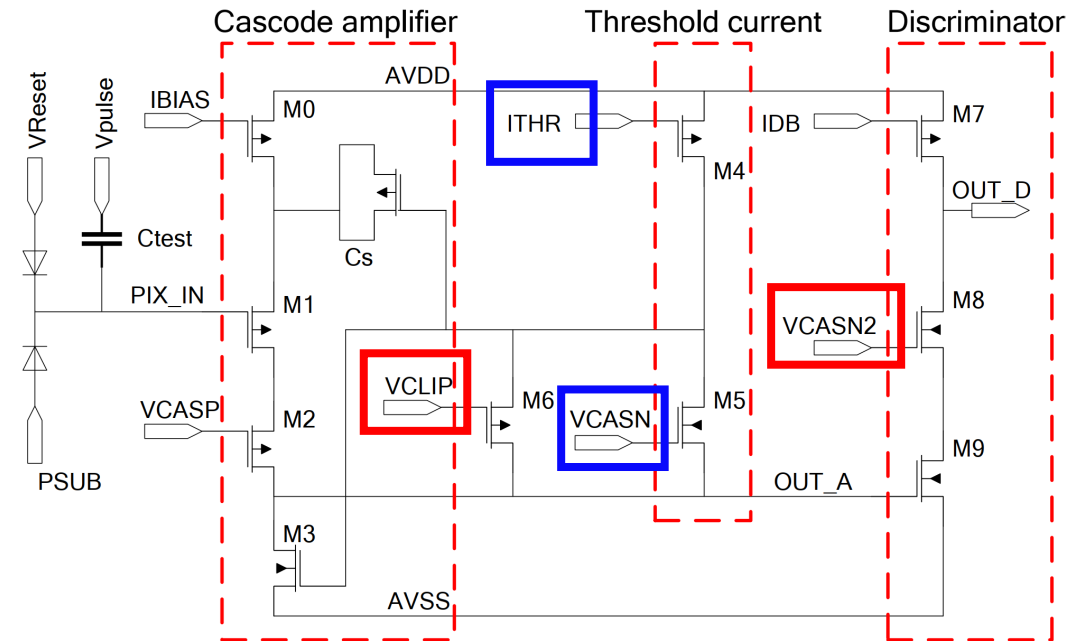
- **Bias Voltage** test need to be operated!

Searching Work-points under Bias

- Designed operating state cannot support all bias V_{sub} levels.
- Work-point Selection from $V_{sub}=0\sim -6V$
 - $VCLIP$, $VCASN2$ adjustment
 - Adjusting $VCASN$ and V_{sub} to keep threshold $\simeq 210 e^-$
 - $ITHR$ scan to achieve distinct thresholds $100\sim 270 e^-$



sensing diode of JadePix-3

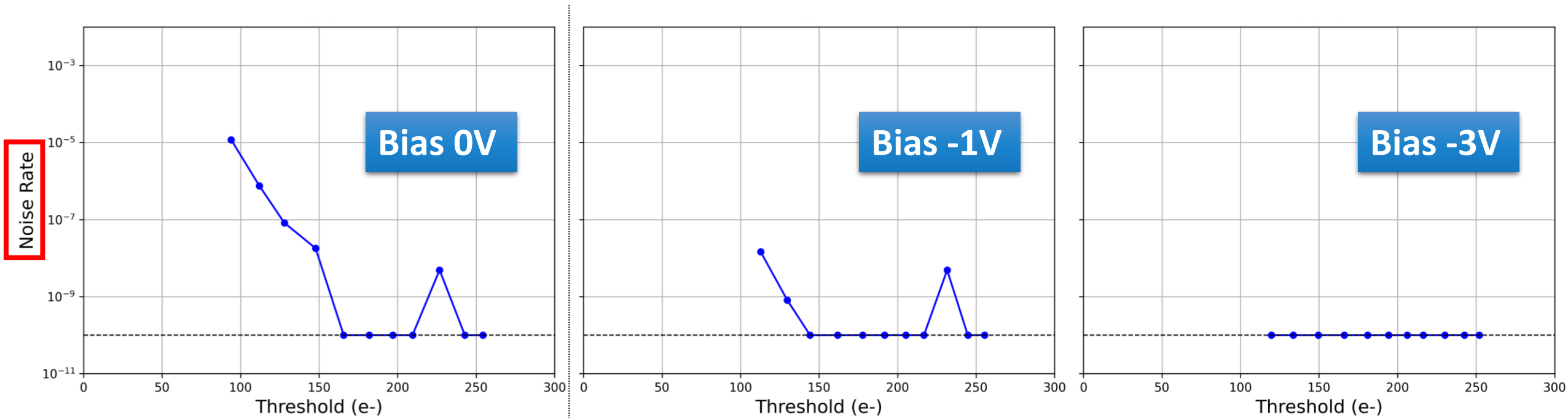


Analog front-end of the sensor



Noise

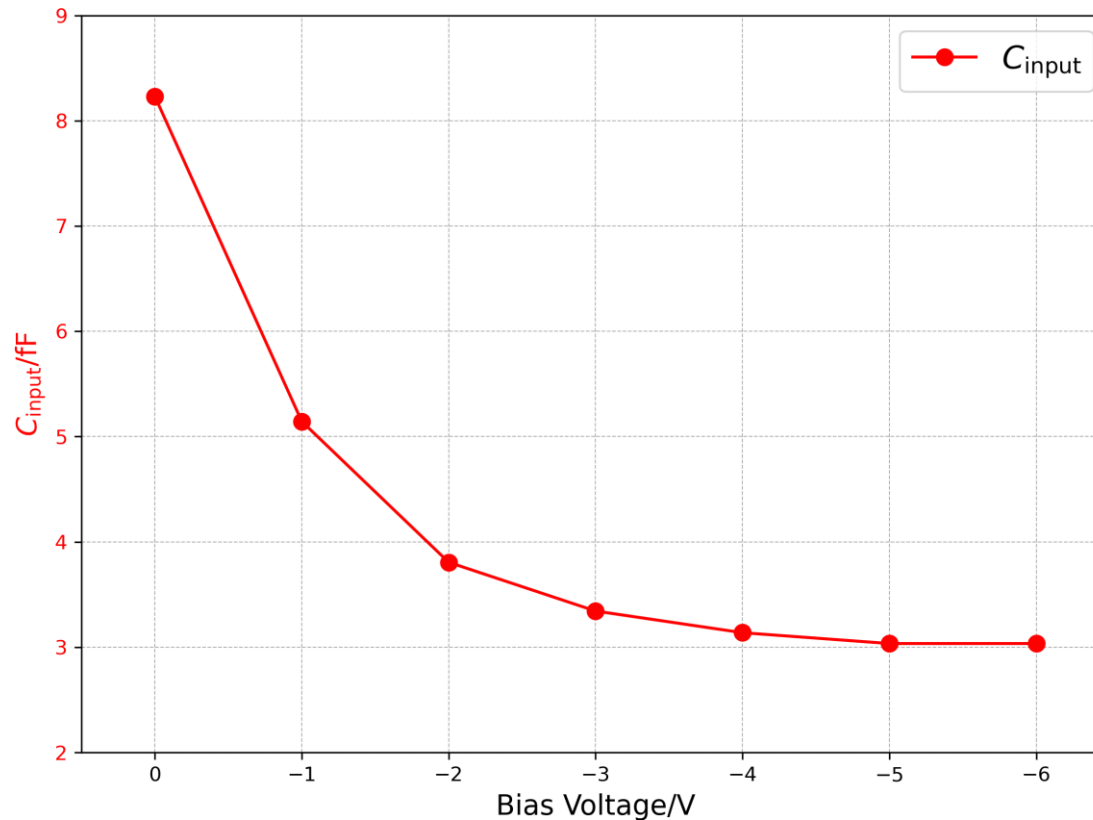
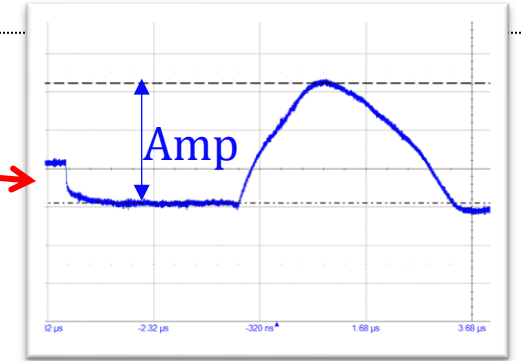
- **Noise Rate** represents the possibility of a pixel hit **without** any particle interactions
 - $R = \frac{\text{Noise Hit Counts}}{\text{Pixel Number} \times \text{Time}}$
- Noise reducing as the threshold increasing
- Noise reducing to **ZERO** as Bias Voltage increasing
 - Bias Voltage improves Noise performance





Input Capacitance

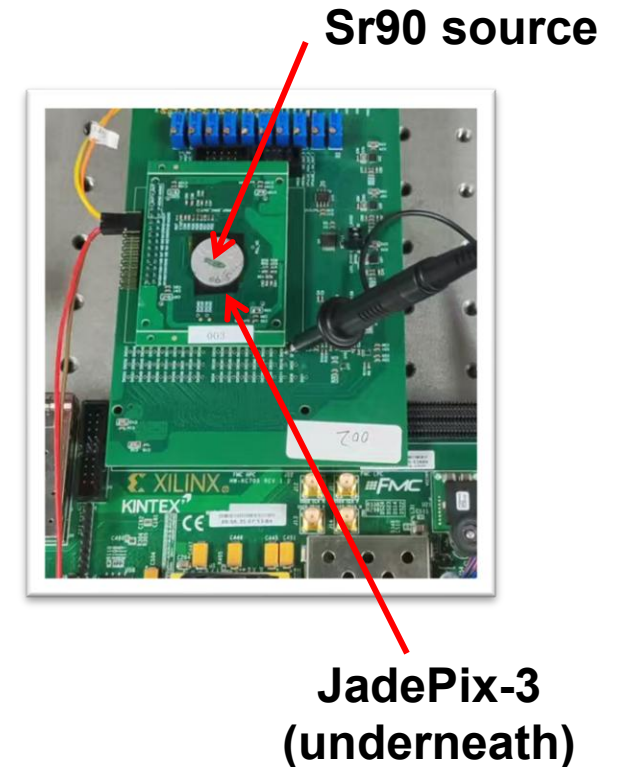
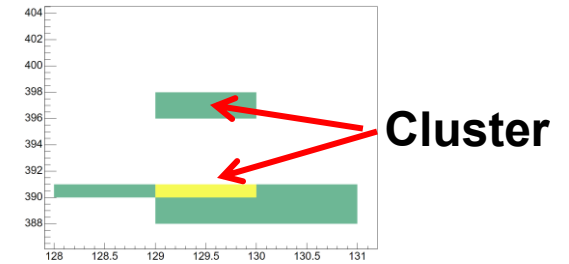
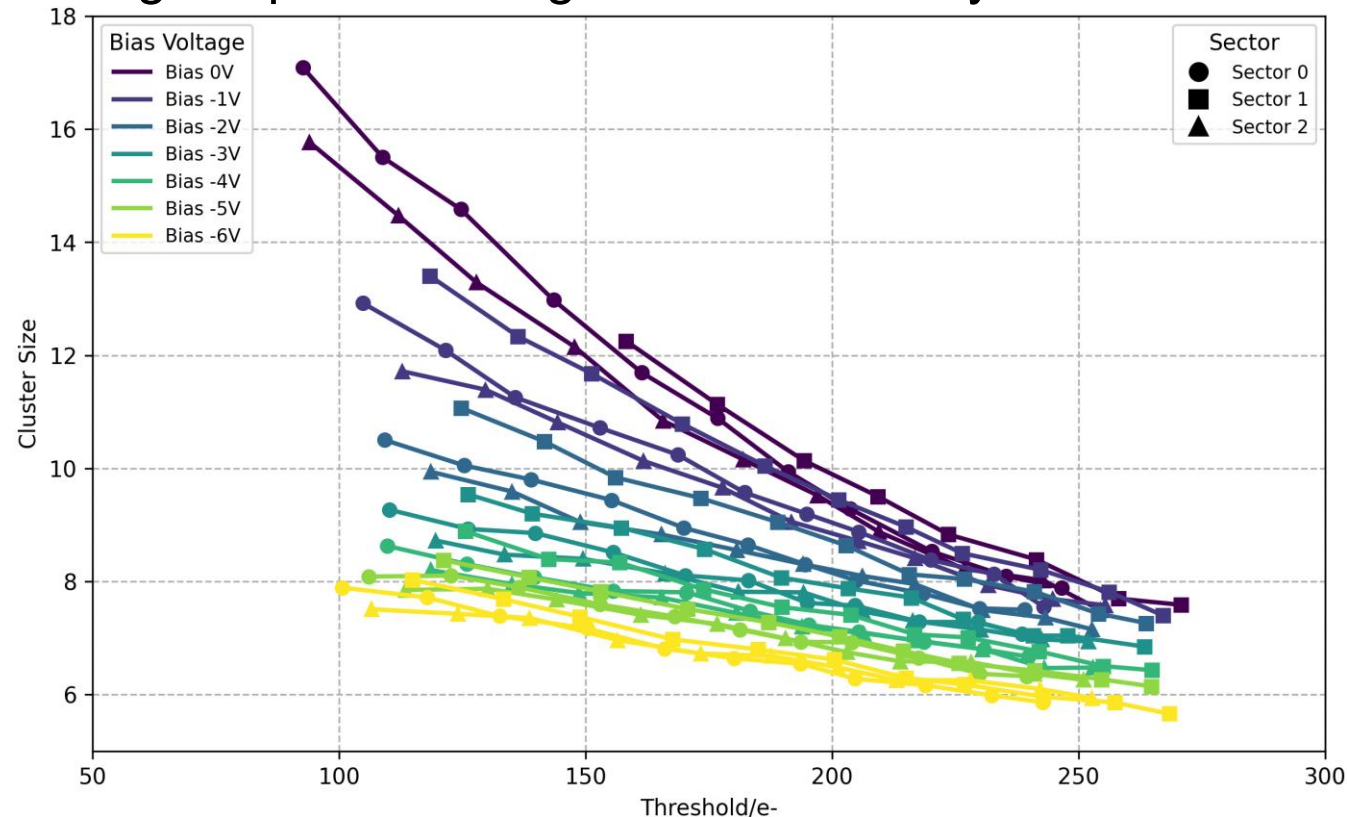
- Input Capacitance, C_{input} accessed by calculating analog response
- Smaller C_{input} increase voltage excursion and improves the SNR
- C_{input} reduced nearly **65%** as Bias Voltage increasing!



$$Amp = \frac{Q_{inject}}{C_{input}} \cdot f_{gain} \cdot f_{sf}$$

Charge Collection Ability

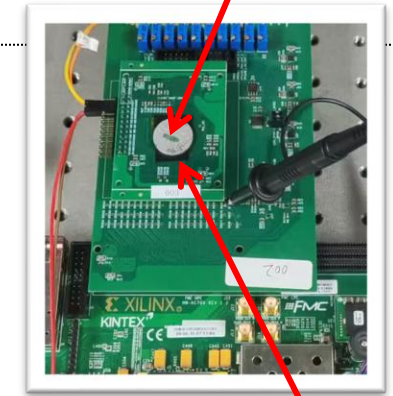
- JadePix-3 exposed to a Sr90(β) source with activity~1200 Bq
- Cluster Size** reflects charge collection & localization ability
- Average Cluster Size reduced nearly **25%** as Bias Voltage increasing
 - Bias Voltage improves charge collection ability!





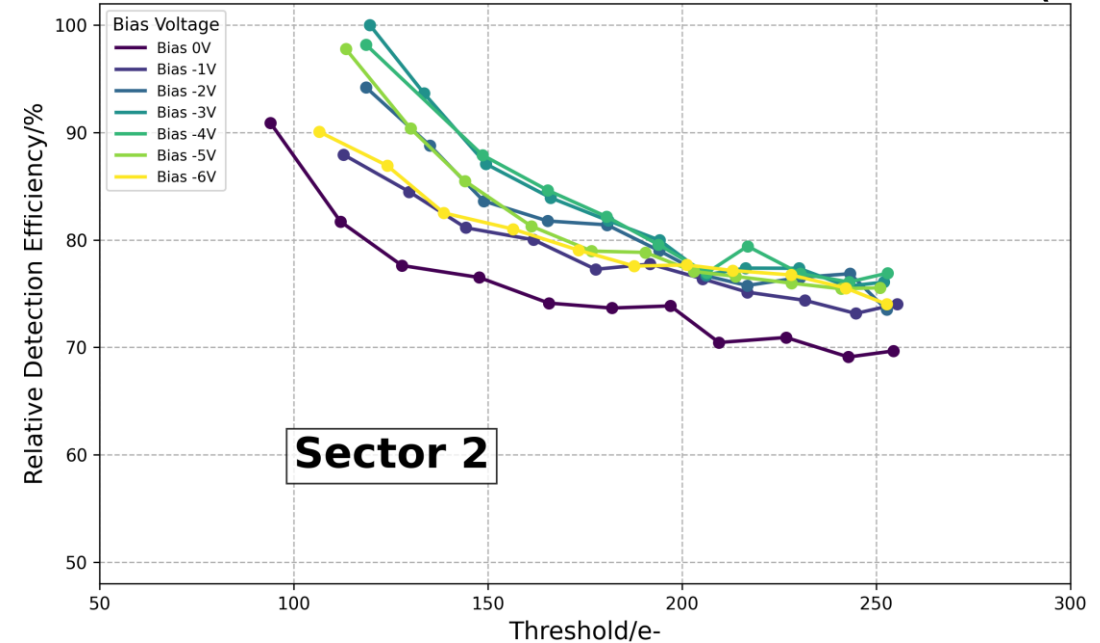
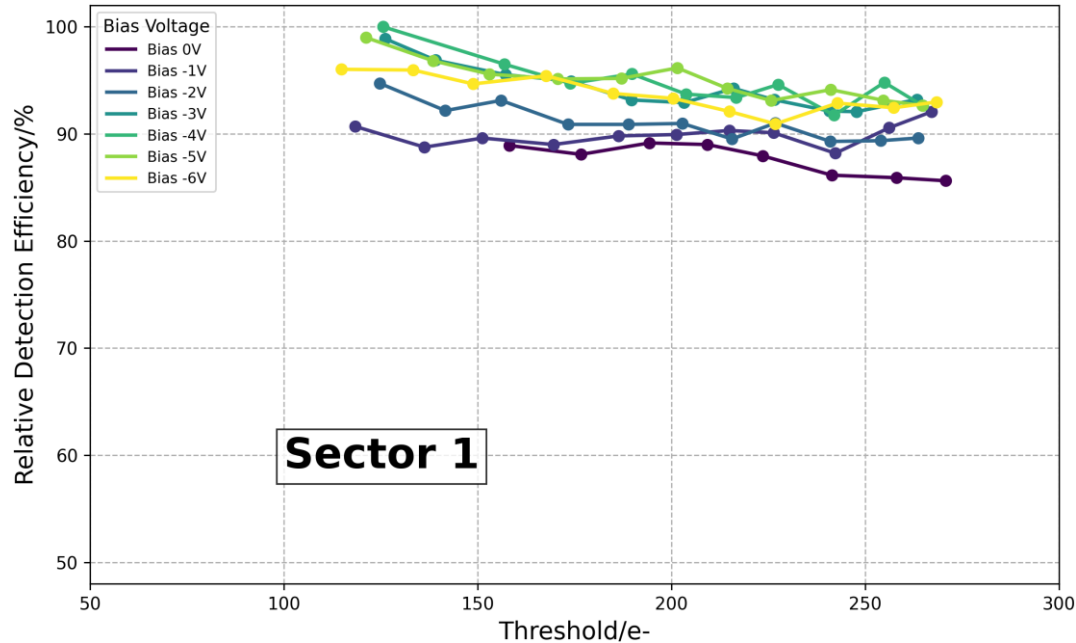
Relative Detection Efficiency

- JadePix-3 exposed to a Sr90(β) source with activity~1200 Bq
- Relative Detection Efficiency** is proportional to cluster numbers accumulated
- Efficiency improved by **10%** from Bias Voltage **0V** to **-5V**
 - Bias Voltage improves detection efficiency!
 - Sector 1(D-flipflop) exceeds Sector 2(RS-flipflop)



Sr90 source

JadePix-3
(underneath)

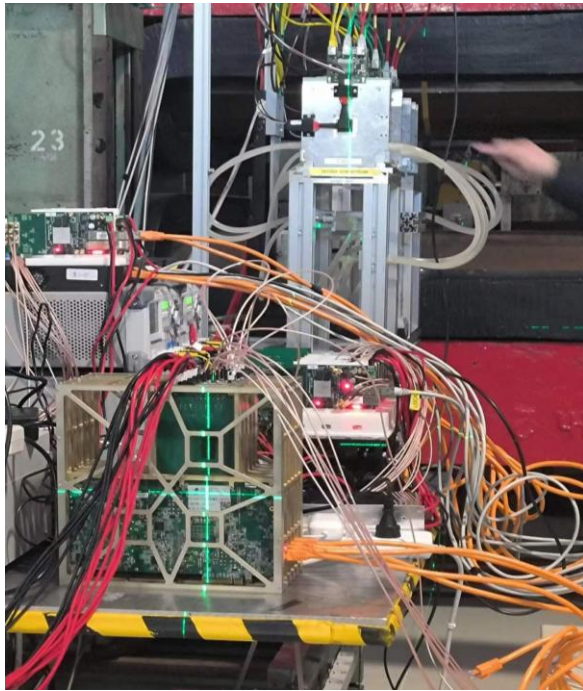




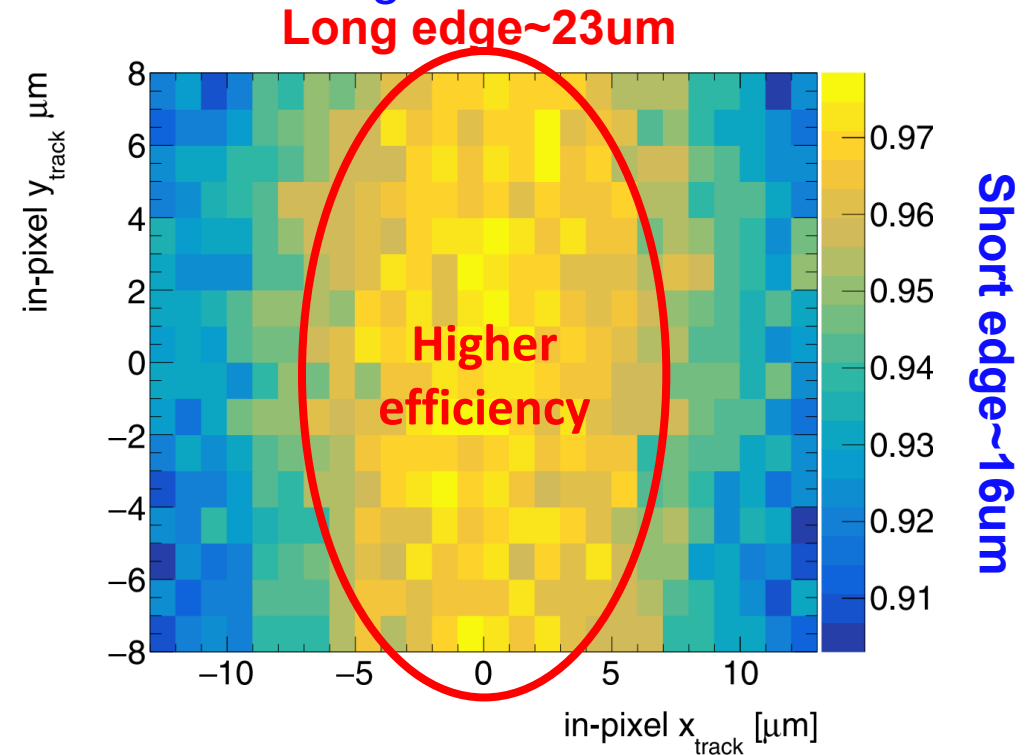
Previous Beam Test @DESY TB21

Sheng DONG, Jia ZHOU, Zhiliang CHEN, Yunpeng LU

- JadePix-3 exposed particle beam, up to 1000 particles per cm^2 and energies from 1 ~ 6 GeV
- In-pixel detection efficiency plot
 - Efficiency ~ 98%, Position Resolution ~ 5 μm
 - higher efficiency at the **long edge** center to the **short edge** center



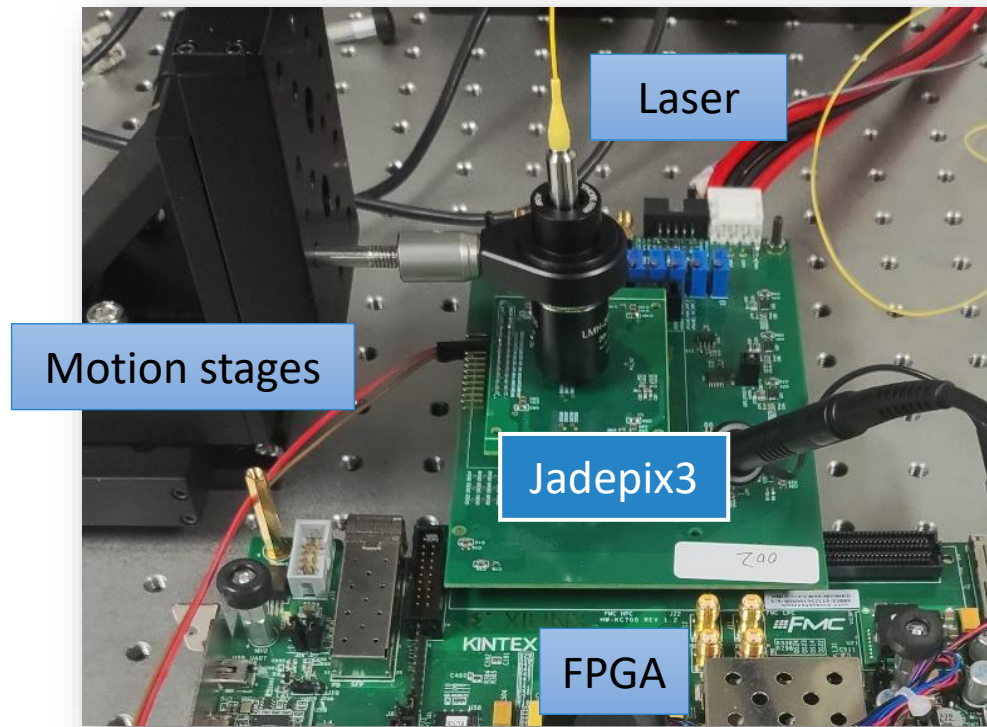
Test Setup @DESY Dec.2022



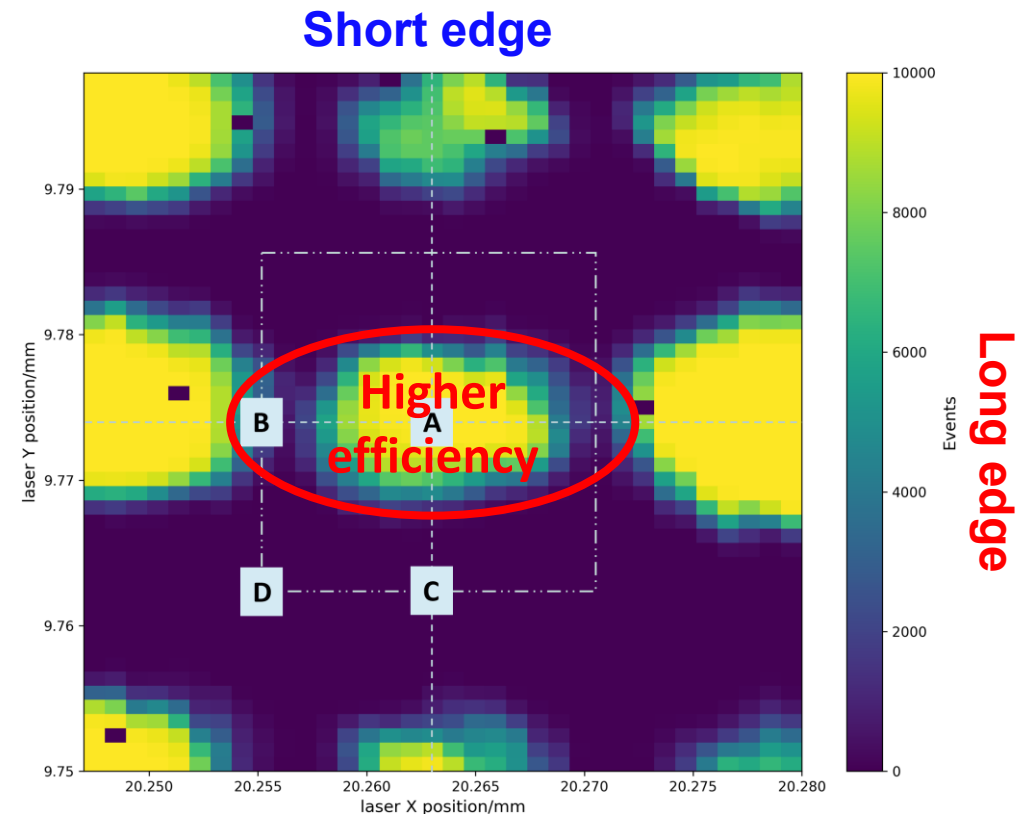
Beam test detection efficiency

Infrared Laser Test

- JadePix-3 exposed to laser beam with 1064nm wavelength
- X-Y scan performed @zero bias
 - Higher hit counts at the **long edge** center to the **short edge** center
 - **Consistent with beam test**



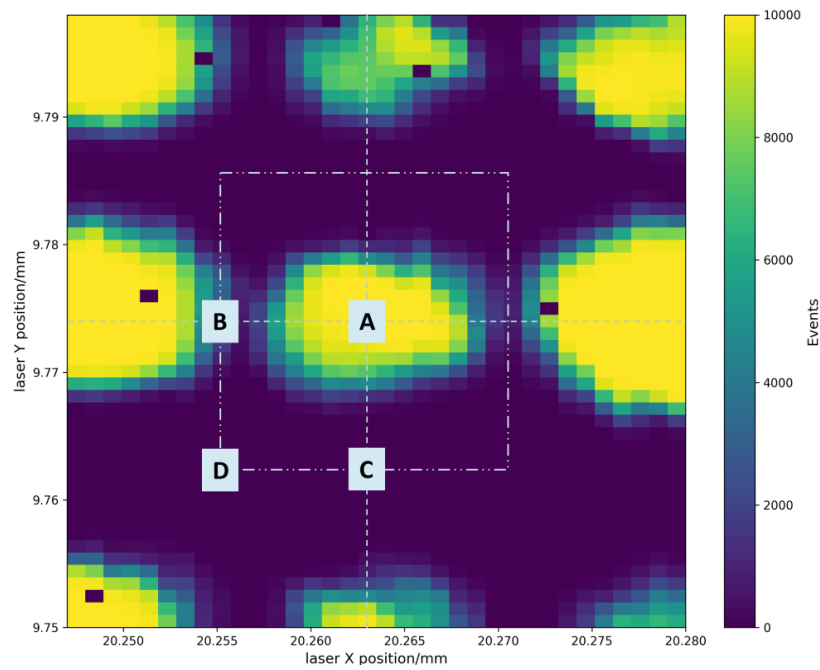
Laser Test Setup



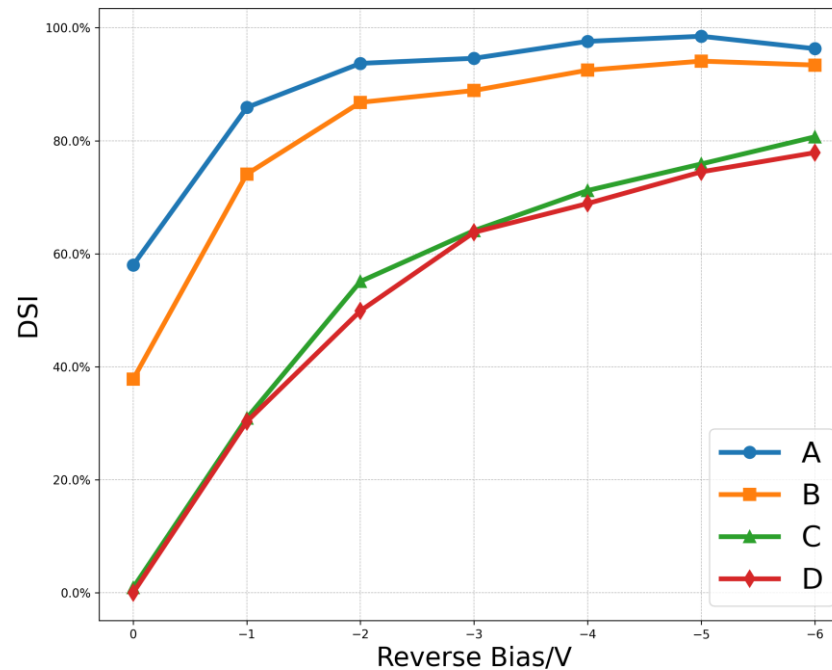
Laser scan

Infrared Laser Test

- **Detection Sensitivity Index (DSI)**, quantifying pixel sensitivity to laser
 - **DSI** = Laser attenuation value where hit counts drop to half the maximum
 - Bias Voltage significantly **improves** overall detection efficiency to laser!



Laser scan



DSI vs. Bias Voltage



Summary

- JadePix-3 is designed for CEPC vertex detector
 - Optimized for high resolution, low power, low mass budget
- Performance enhanced under Bias condition:

Noise	Input Capacitance	Charge Collection	Efficiency	Other performance
Reduce to ZERO	Reduced 65%	Improve 25%	Enhanced 10%	

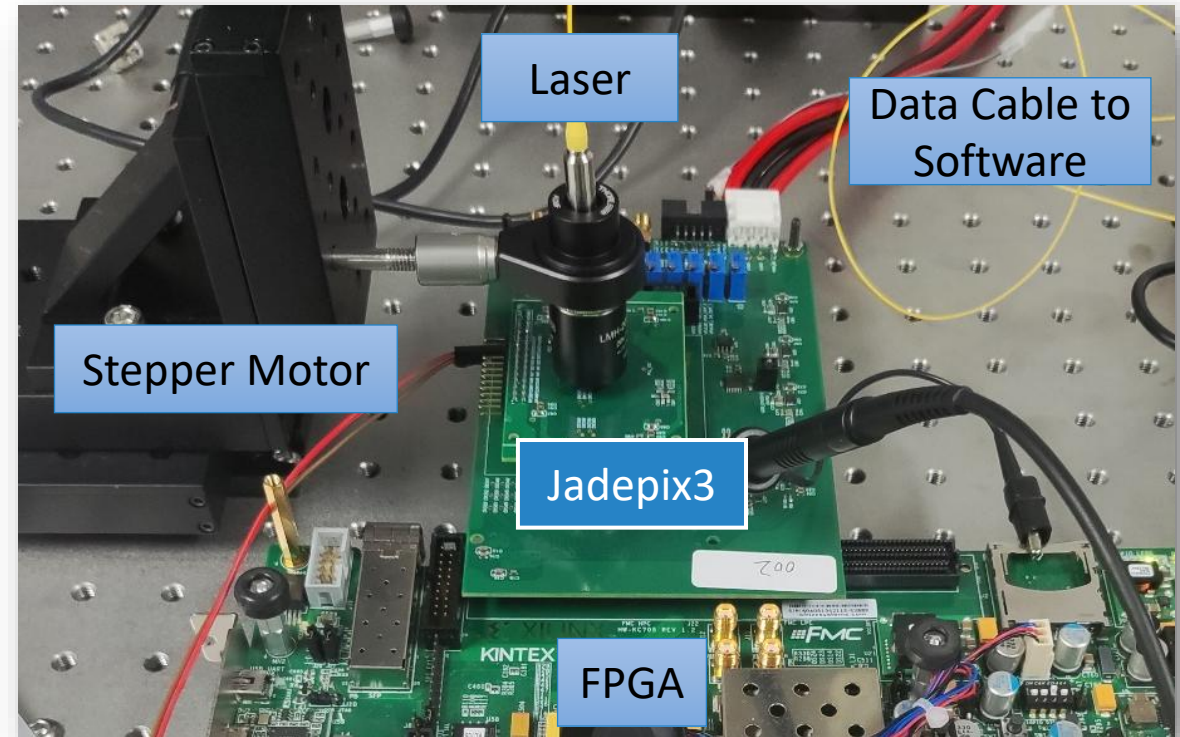
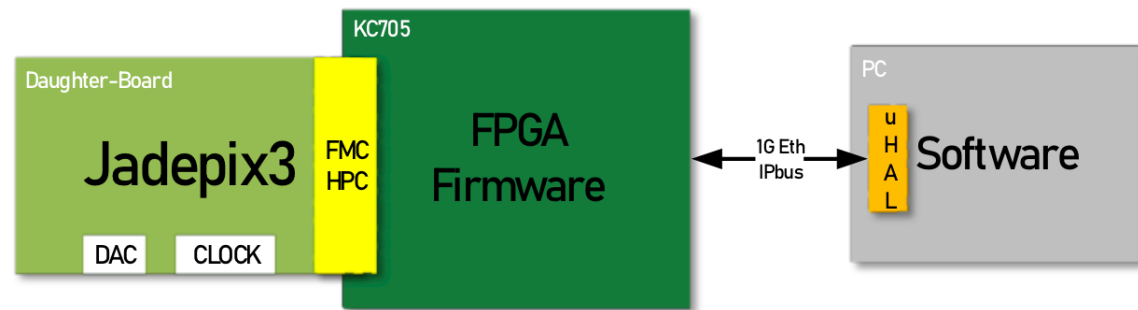
- Beam Test in preparation

感谢高能所卢云鹏老师
提供的支持！

Back up



Test System Setup@USTC

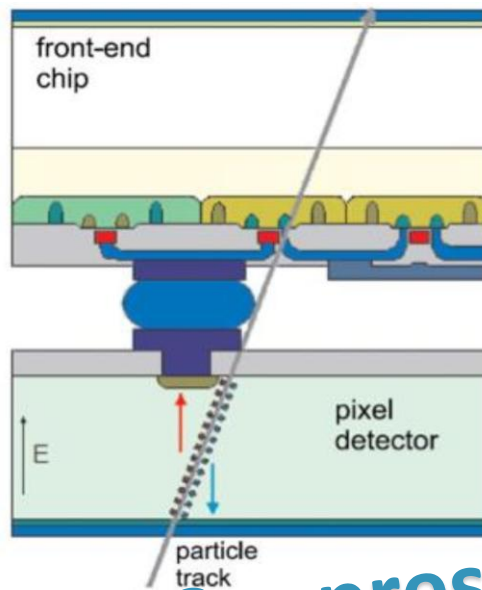




Silicon pixel detector

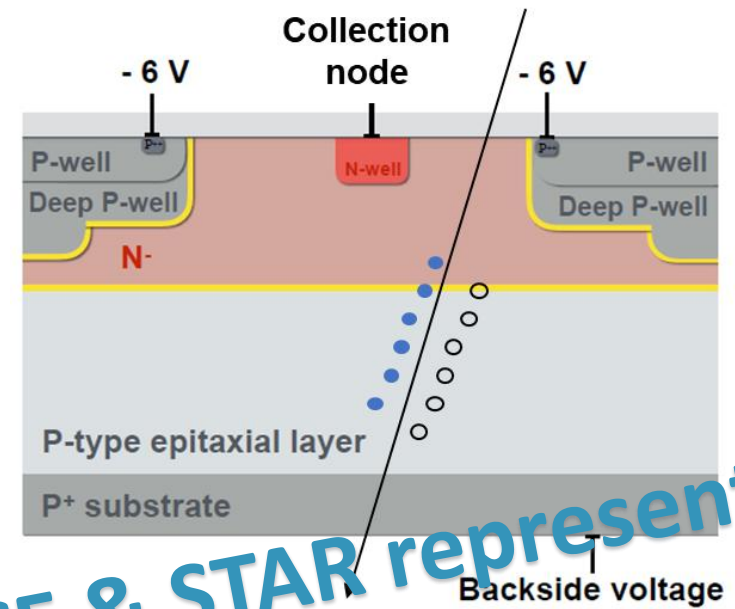
Hybrid

- Separately optimize sensor and FE-chip for very high radiation environment
- Fine pitch bump bonding to connect sensor and readout chip



Monolithic

- Charge generation volume **integrated** into the ASIC, but many different variants!
- Thin monolithic CMOS sensor, on-chip digital readout architecture



ATLAS & CMS representative

ALICE & STAR representative



Rolling Shutter(RS) Mode in JadePix-3

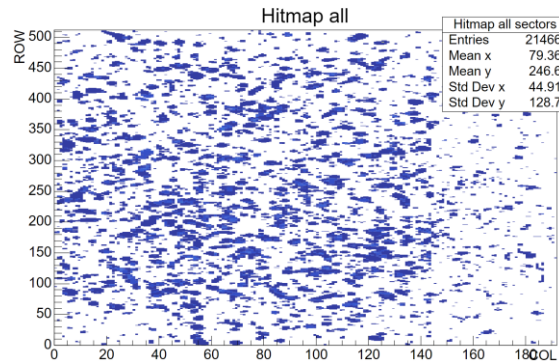
- Hit registered in each pixel has to be processed **fast**

- Hit position (col. and row address) encoded
- Time stamp attached
- Register reset for the next hit



✓ Rolling Shutter Mode deployed

- ✓ row address encoding
- ✓ iterate over all rows → Take a shutter
- ✓ Multiple frames → Long exposure



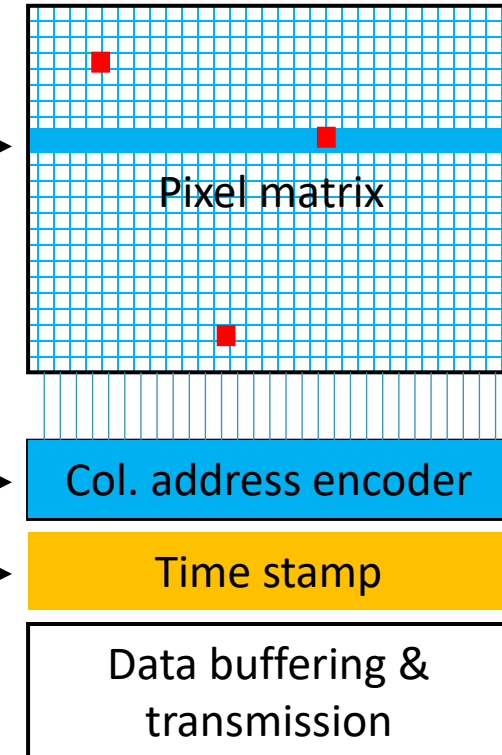
‘Photo’ took by RS
under radio-source
for 10,000frames

row address information
extracted from the row
selecting sequence
(RS)

col address encoded at
the end of columns

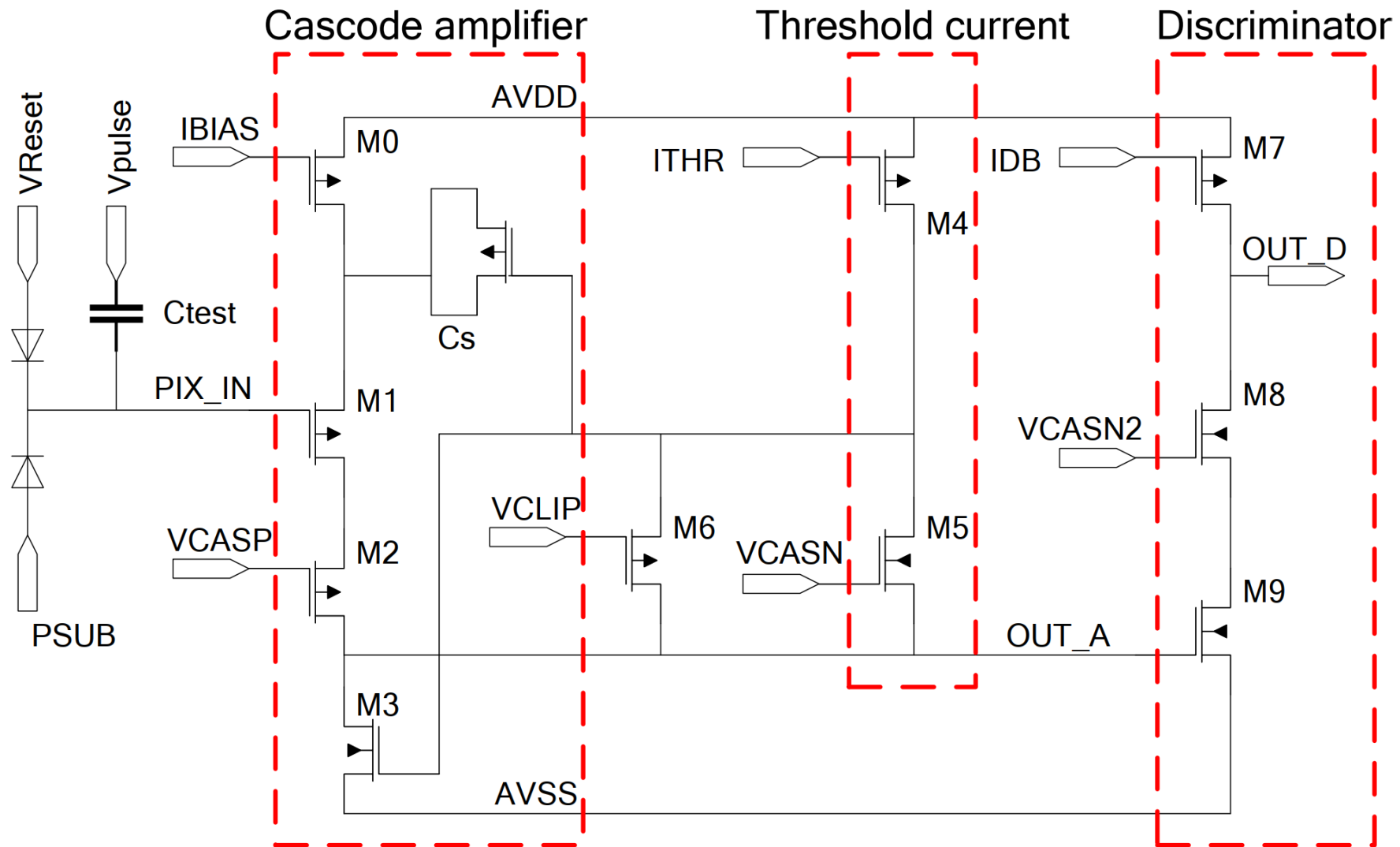
Time stamp attached to
the generated hit address

JadePix-3 flow





Front-end Circuit



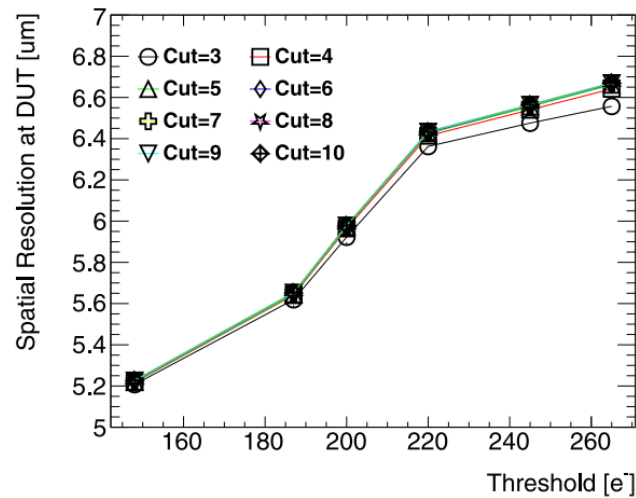


Beam Test Result

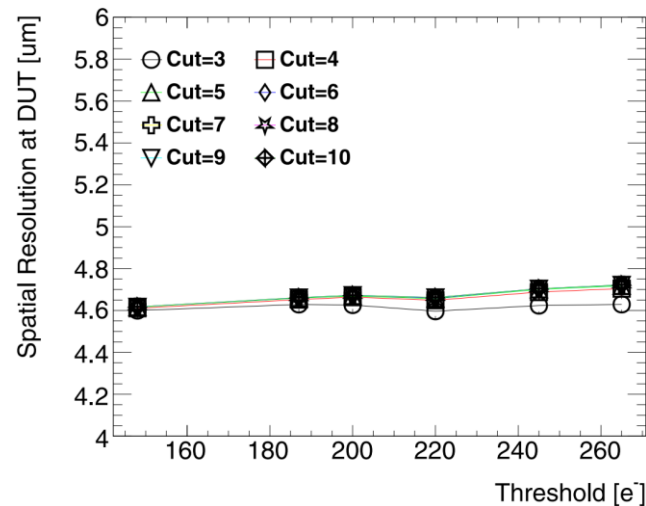
@DESY

Sheng Dong, Zhiliang Chen

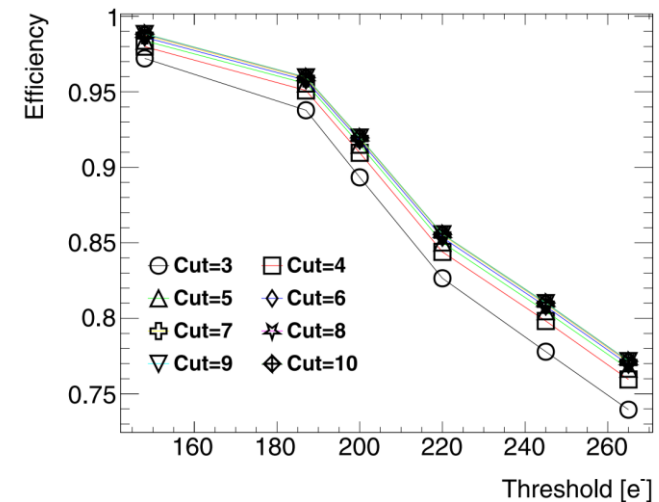
- Electron beam energy = 5.8GeV
 - Demonstrated excellent spatial resolutions of 5.2 & 4.6 μm in two dimensions.
 - Threshold scan performed below:



X res. vs. threshold



Y res. vs. threshold



Efficiency vs. threshold



Requirement of Vertex detector @ CEPC

- Physics goals @ CEPC
 - Identify b/c quarks and tau leptons from Higgs
 - Perform a precise measurements of the Z boson



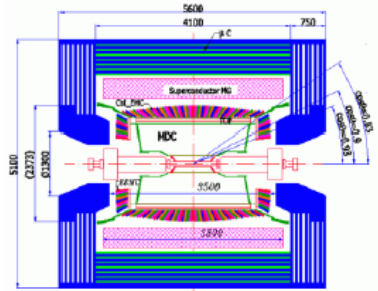
- Require a 3 μm spatial resolution
- Fast readout speed of 20 μs
- Very low mass budget ($<0.15\% X_0$ / layer)
- Adequate radiation tolerance

JadePix
MAPS

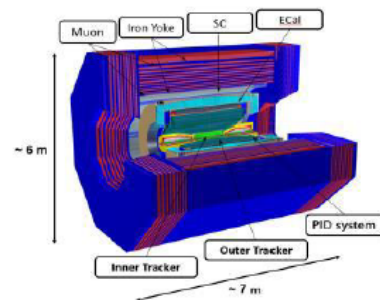


Requirements for e^+e^- @ different energy regions

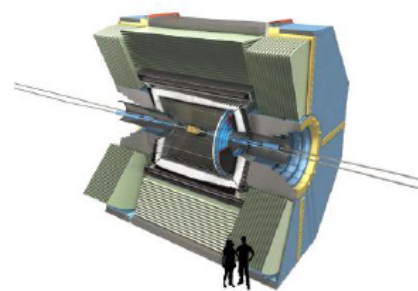
- Monolithic detector can meet different experimental needs
 - Design & optimize pixel chips for specific experimental needs



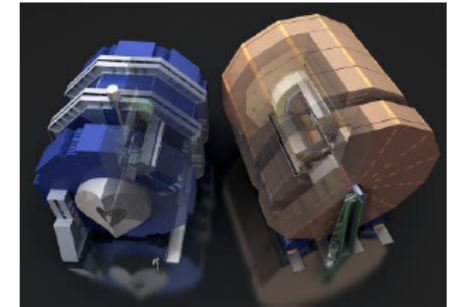
Charm: 2-7 GeV
BESIII upgrade / STCF
Sensitive to mass budget



Bottom: ~10.58 GeV
BELLEII upgrade
Highest luminosity



Higgs: 240-250 GeV
CEPC / ILC
Highest precision

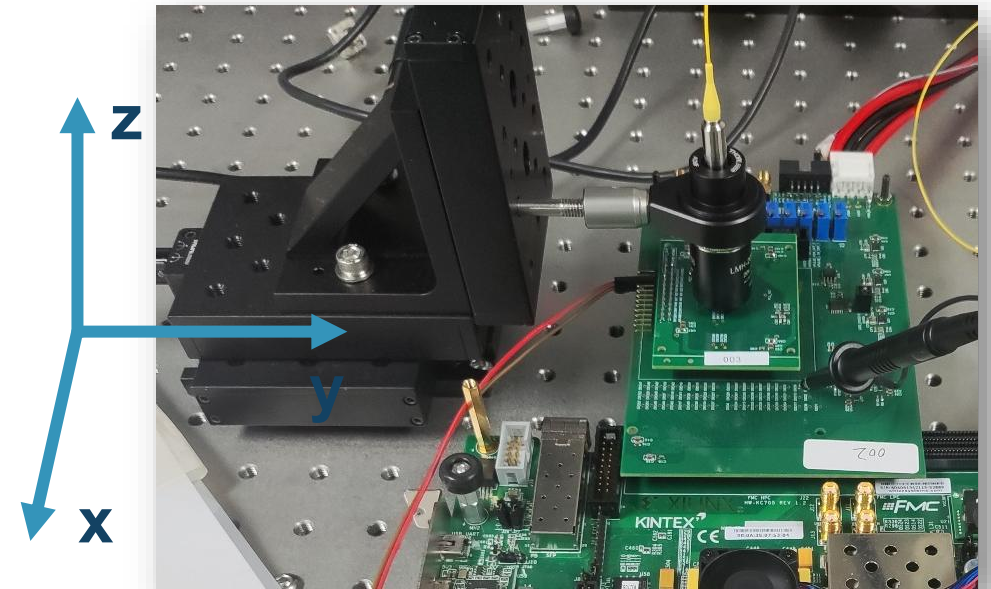
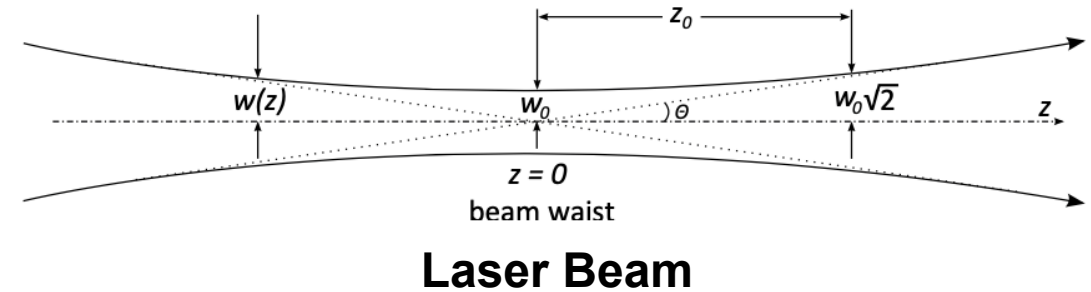


**High precision, fast readout,
low power, low mass budget**

← MAPS

Infrared Laser Test

- Test procedure
 - 1. Scan in z-direction, zero bias to determine the position of beam waist.
 - 2. Scan in xy-direction, 0V/-1V/-2V bias and tune 95%/99%.
 - 3. *Residual=Reconstruct - Motor*
 - Gauss fit
 - Case-by-case statistics
 - Point-by-point statistics





Infrared Laser Test

Bias(V),Tune	Point-by-point statistics		Case-by-case statistics	
	Column Resolution/um	Row Resolution /um	Column Resolution/um	Row Resolution /um
0,95%	1.92	1.68	3.26	3.21
0,99%	4.16	1.97	4.67	3.36
-1,95%	2.33	1.75	3.13	2.74
-1,99%	2.05	2.29	2.96	3.20
-2,95%	3.24	1.76	3.71	2.63
-2,99%	2.49	1.78	3.11	2.65